

**FEATURES**

- \* 0.7 inch (17.22mm) DIGIT HEIGHT
- \* CONTINUOUS UNIFORM SEGMENTS
- \* LOW POWER REQUIREMENT
- \* EXCELLENT CHARACTERS APPEARANCE
- \* HIGH BRIGHTNESS & HIGH CONTRAST
- \* WIDE VIEWING ANGLE
- \* SOLID STATE RELIABILITY
- \* CATEGORIZED FOR LUMINOUS INTENSITY
- \* **LEAD-FREE PACKAGE**

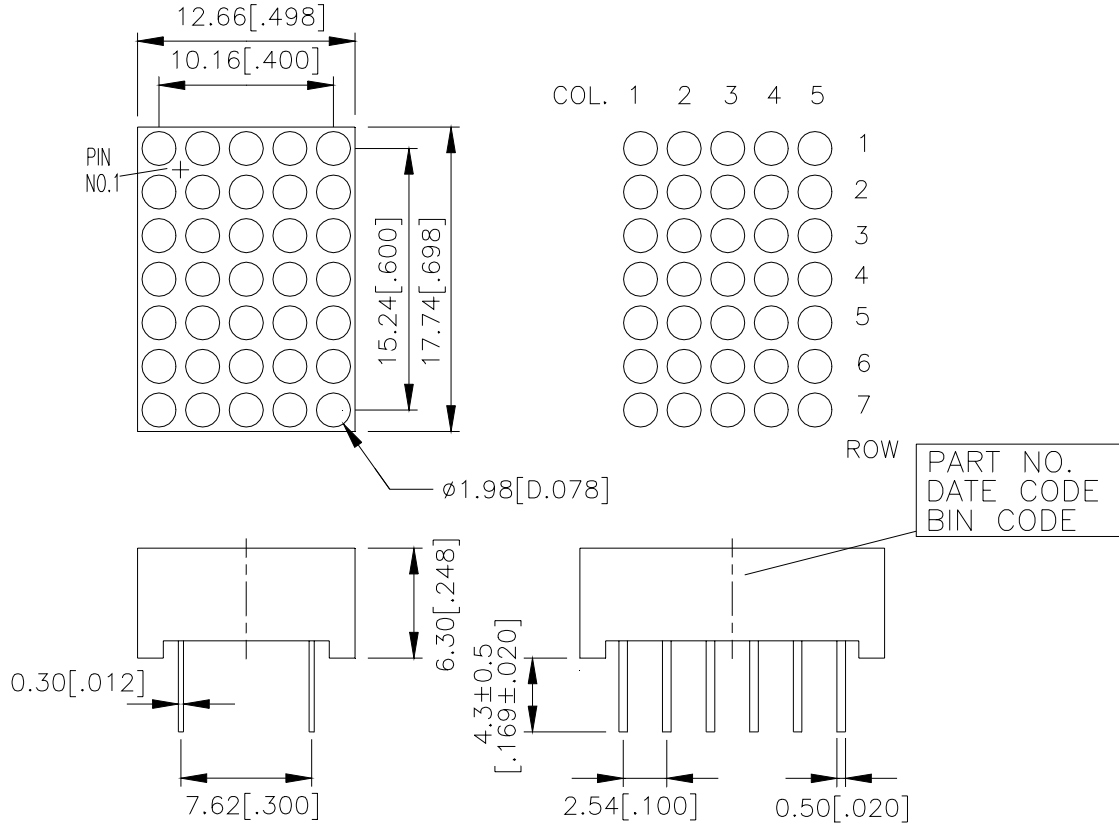
**DESCRIPTION**

The LTP-757KR-NB is a 0.7inch (17.22mm) matrix height 5 x 7 dot matrix display. This device uses AllnGap Super Red LED chips (AllnGaP epi on GaAs substrate). The display has black face and white dots.

**DEVICE**

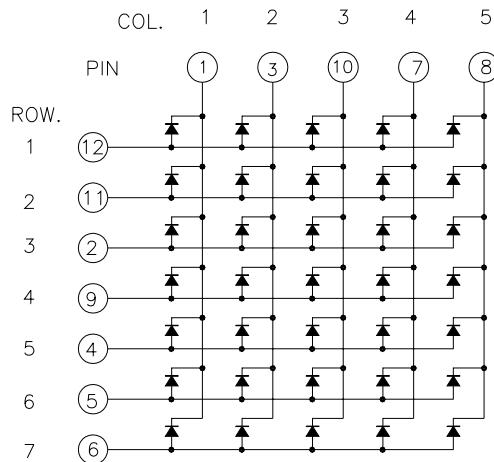
<b>PART NO.</b>	<b>DESCRIPTION</b>
AllnGaP Hyper Red	Cathode Column
LTP-757KR-NB	Anode Row

## PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are  $\pm 0.25$ -mm (0.01“) unless otherwise noted.

## INTERNAL CIRCUIT DIAGRAM



**PIN CONNECTION**

<b>No.</b>	<b>CONNECTION</b>
1	CATHODE COLUMN 1
2	ANODE ROW 3
3	CATHODE COLUMN 2
4	ANODE ROW 5
5	ANODE ROW 6
6	ANODE ROW 7
7	CATHODE COLUMN 4
8	CATHODE COLUMN 5
9	ANODE ROW 4
10	CATHODE COLUMN 3
11	ANODE ROW 2
12	ANODE ROW 1

**ABSOLUTE MAXIMUM RATING**

PARAMETER	MAXIMUM RATING	UNIT
Average Power Dissipation Per dot	40	mW
Peak Forward Current Per dot	90	mA
Average Forward Current Per dot	15	mA
Derating Linear From 25 <sup>0</sup> C Per dot	0.2	mA/ <sup>0</sup> C
Reverse Voltage Per dot	5	V
Operating Temperature Range	-35 <sup>0</sup> C to +85 <sup>0</sup> C	
Storage Temperature Range	-35 <sup>0</sup> C to +85 <sup>0</sup> C	
Soldering Conditions : 1/16 inch below seating plane for 3 seconds at 260 <sup>0</sup> C		

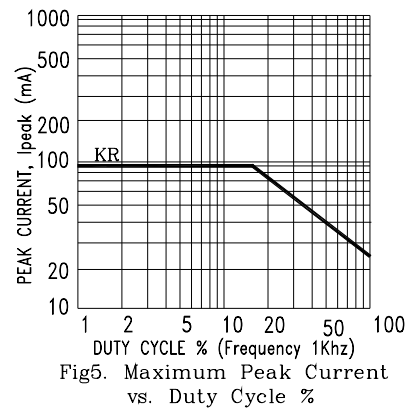
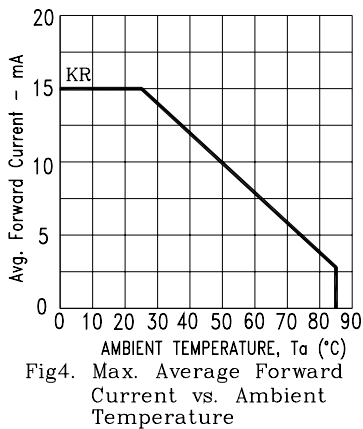
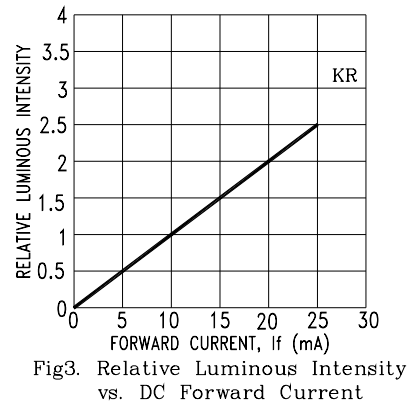
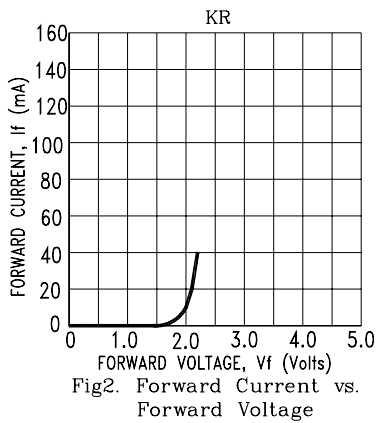
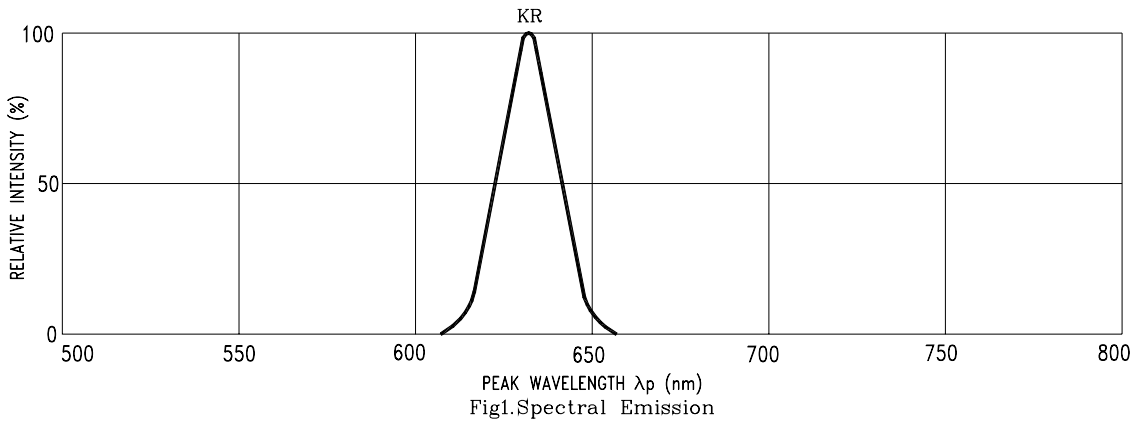
**ELECTRICAL / OPTICAL CHARACTERISTICS AT T<sub>A</sub>=25<sup>0</sup>C**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I <sub>v</sub>	630	1732		μcd	I <sub>F</sub> =32mA , 1/16Duty
Peak Emission Wavelength	λ <sub>p</sub>		639		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		20		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		631		nm	I <sub>F</sub> =20mA
Forward Voltage Per dot	V <sub>F</sub>		2.0	2.6	V	I <sub>F</sub> =20mA
Reverse Current Per dot	I <sub>R</sub>			100	μA	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio (Similar Light Area)	I <sub>v-m</sub>			2:1		I <sub>F</sub> =32mA , 1/16Duty

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

**TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES**

(25°C Ambient Temperature Unless Otherwise Noted)



NOTE : KR=AlInGaP SUPER RED